High efficiency operation • AEC-Q101 gualified available:

- of 260 °C
- please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 gualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test Polarity: as marked

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V60DM120C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	120	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	60	Δ.	
	per diode		30	- A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I _{FSM}	320	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +175	°C	

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- Automotive ordering code: base P/NHM3
- Meets MSL level 1, per J-STD-020, LF maximum peak
- Material categorization: for definitions of compliance

V60DM120C-M3, V60DM120CHM3 Vishay General Semiconductor

Dual High-Voltage TMBS[®] (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.43$ V at $I_F = 5$ A

eSMP[®] Series SMPD (TO-263AC) Top View **Bottom View**

Cathode

DESIGN SUPPORT TOOLS AVAILABLE

Anode 1 O

Anode 2 C



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 30 A			
V _{RRM}	120 V			
I _{FSM}	320 A			
V_F at I_F = 30 A (T_A = 125 °C)	0.70 V			
T _J max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			



COMPLIANT

HALOGEN

FREE





V60DM120C-M3, V60DM120CHM3

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.51	-	V
	I _F = 15 A			0.68	-	
	I _F = 30 A			0.87	0.97	
	$I_F = 5 A$	T _A = 125 °C		0.43	-	
	I _F = 15 A			0.58	-	
	I _F = 30 A			0.69	0.77	
Reverse current at rated V _R per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	0.01	-	mA
		T _A = 125 °C		5	-	
	$V_{-} = 120 V_{-}$	T _A = 25 °C		-	0.7	
	V _R = 120 V	T _A = 125 °C		10	35	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V60DM120C	UNIT	
Typical thermal resistance	per device	$R_{\theta JC}$	0.95	°C/W	
	per device	R _{0JA} (1)(2)	45		

Notes

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

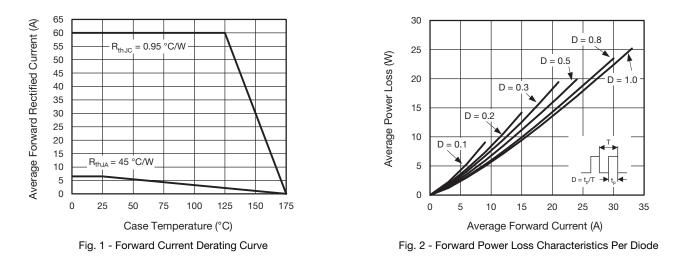
⁽²⁾ Free air, without heatsink

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V60DM120C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel	
V60DM120CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel	

Note

⁽¹⁾ AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)



Revision: 18-Mar-2019

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V60DM120C-M3, V60DM120CHM3

Vishay General Semiconductor

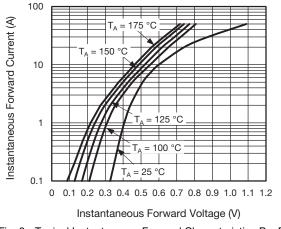
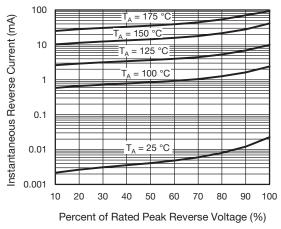


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode





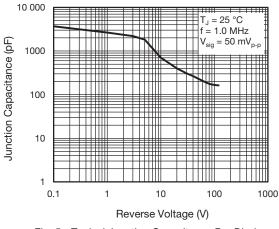


Fig. 5 - Typical Junction Capacitance Per Diode

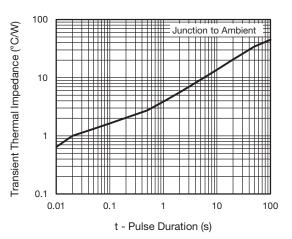


Fig. 6 - Typical Transient Thermal Impedance Per Device

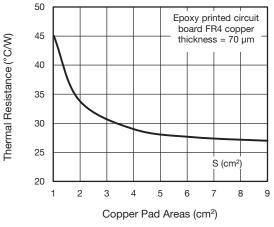


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

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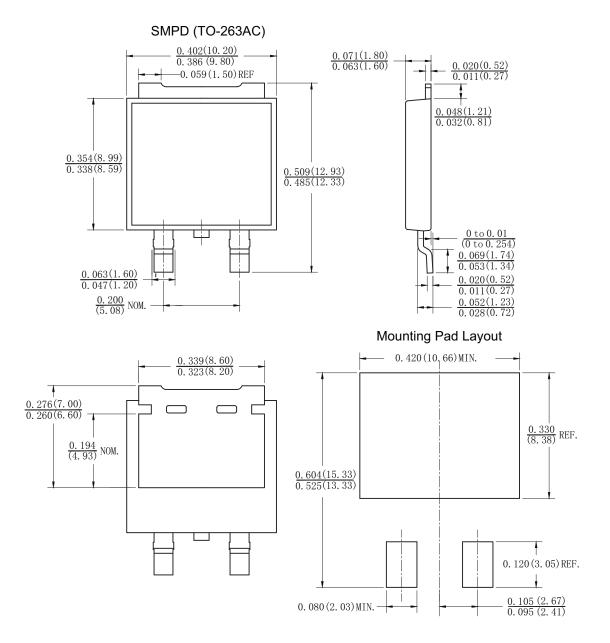
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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